2/4 Outputs Ultra-Low Additive Jitter PCIe 1/2/3/4/5 Clock Buffer for Automotive

Features

- Two (SYA75603A/03B) and Four (SYA75604A/04B) PCIe 1/2/3/4/5 Compliant Outputs
- Ultra-Low Additive Jitter 10 fs (PCIe Gen5)
- Supports Frequencies of up to 250 MHz
- · Transparent for Spread Spectrum
- Supports 1.8V ±10%, 2.5V ±10% and 3.3V ±10% Power Supplies
- Outputs Low Power HCSL with Embedded 85Ω (SYA75603A/04A) and 100Ω (SYA75603B/04B) Termination Resistors
- Individual Glitch Free Output Enable (OExb) Control Pins
- Accepts DC Coupled HCSL Input Signal and AC Coupled PECL, LVDS and CML
- Extended Temperature Range: -40°C to +105°C
- 3 mm x 3 mm VQFN Package

Applications

- ADAS
- · PCIe Based SSD drives
- · Infotainment System

General Description

The SYA75603A, SYA75603B, SYA75604A, and SYA75604B are industry leading PCIe clock buffers with ultra-low additive jitter:

- 10 fs (PCle 5.0)
- 20 fs (PCIe 3.0/4.0)
- 52 fs in the 12 kHz to 20 MHz band

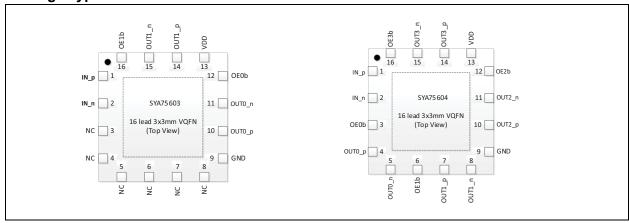
They can be used in all PCle 1/2/3/4/5 common clock and SRIS applications.

SYA75603A/03B and SYA75604A/04B are two and four output (respectively) PCIe clock buffers with glitch free per-output enable/disable control hardware pins. Both devices are packaged in a 3 mm x 3 mm VQFN.

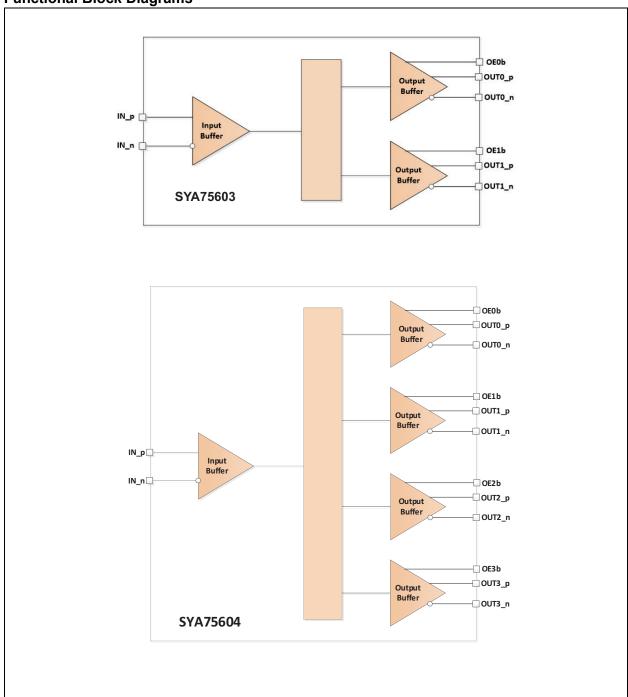
The SYA75603A/03B/604A/04B have embedded low-dropout regulators (LDO) for superior power noise supply rejection. They support 1.8V, 2.5V, and 3.3V supplies with tolerance of $\pm 10\%$ which exceeds $\pm 9\%$ required by PCIe Card Electro Mechanical Specification.

All parts are Automotive Grade 2 compliant: -40°C to +105°C

Package Types



Functional Block Diagrams



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

Supply Voltage (V _{DD})	–0.5V to +4.6V
Input Voltage (V _{IN})	
Input ESD Protection (HBM)	2 kV

Operating Ratings ‡

1.8V Operating Voltage (V _{DD})	+1.62V to +1.98V
2.5V Operating Voltage (V _{DD})	
3.3V Operating Voltage (V _{DD})	

- **† Notice:** Permanent device damage may occur if absolute maximum ratings are exceeded. This is a stress rating only and functional operation is not implied at conditions other than those detailed in the operational sections of this data sheet. Exposure to absolute maximum ratings conditions may affect device reliability.
- **‡ Notice:** The data sheet limits are not guaranteed if the device is operated beyond the recommended operating conditions.

ELECTRICAL CHARACTERISTICS

Electrical Characteristics: V_{DD} = 3.3V ±10%, 2.5V±10%; 1.8V±10% T_A = -40°C to +105°C, unless noted.

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Current Consumption						1
Core Device Current	I _{DD}	_	9	13		All outputs disabled
Current dissipation per each LP-HCSL output (100Ω)	I _{OUT_HCSL_100Ω}	_	3.5	3.9	mA	Note 1
Current dissipation per each LP-HCSL output (85Ω)	I _{OUT_HCSL_85Ω}	_	4.0	4.4	mA	Note 1
Power Supply Noise Reje	ction Ratio Cl	naracteris	tics			
Power Supply Noise Rejection Ratio	PSNRR _{HSCL}	_	70	_	dB	Note 3, 100 mV _{PP} , 100 kHz noise injected to V _{DD} . Clock Frequency 100 MHz, V _{DD} = 3.3V
Input Characteristics						
Input Slew Rate	SR _{IN}	0.6	_		V/ns	Note 3
Differential Input High Voltage	V _{IH}	0.15	_	_	٧	_
Differential Input Low Voltage	V _{IL}	_	_	-0.15	V	_
Input Voltage Swing	V _{SWING}	0.15	_		V_{DIFF}	_
Absolute Crossing Point Voltage	V _{CROSS}	0.25	_	0.55	٧	Note 3
Variation of V _{CROSS} Over All Edges	V _{CROSS_DELTA}	_	_	0.14	٧	Note 3
Voltage High for Output Enable	V _{IH_OE}	0.7* V _{DD}	_	_	V	_
Voltage Low for Output Enable	V _{IL_OE}	_	_	0.3* V _{DD}	V	_
Input Leakage Current	I _{IL_IN}	- 5	_	5	μΑ	$V_{IN} = V_{IN(MAX)}, V_{IN} = GND$
Input Capacitance	C _{IN}	_	_	5	pF	Note 3
Input Leakage Current for OExb Inputs (Includes Current due to Pull-Down Resistors)	I _{IL_OE}	- 5	_	50	μΑ	$V_{IN} = V_{DD}, V_{IN} = GND$

ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Characteristics: V_{DD} = 3.3V ±10%, 2.5V±10%; 1.8V±10% T_A = -40°C to +105°C, unless noted.

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Single Ended Input Common Mode Voltage (IN_p) (HCSL Common Mode)	V _{SIC}	0.25		0.55	٧	_
Single Ended Input Voltage Swing for IN_p	V_{SID}	0.3		1.45	٧	_
Maximum Input Voltage	$V_{IN}(MAX)$	_	_	1.15	V	_
Minimum Input Voltage	V _{IN} (MIN)	-0.3	_	_	V	_
Input Frequency (Differential)	f _{IN}	0	_	250	MHz	Note 2
Input Frequency (Single Ended)	f _{IN_SE}	0		250	MHz	Note 2
Input Duty Cycle	DC	35	_	65	%	Note 3

- Note 1: Tested with 100 MHz clock with outputs driving 5" long trace terminated with 2 pF capacitors to ground.
 - 2: Output Enable control pins are synchronous with the input clock and it takes four rising edges before outputs get enabled and five rising edges before outputs get disabled. Hence the minimum input frequency is greater than 0 Hz. Once the outputs are enabled the input clock frequency can be reduced to 0 Hz.
 - 3: Ensured by design and/or characterization, not tested in production.

OUTPUT ELECTRICAL CHARACTERISTICS

Electrical Characteristics: V_{DD} = 3.3V ±10%, 2.5V±10%; 1.8V±10% T_A = -40°C to +105°C, C_{LOAD} = 2 pF unless noted.

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Rising Edge Rate	_	1	2.5	4	V/ns	Note 2, Note 3
Falling Edge Rate	_	1	2.5	4	V/ns	Note 2, Note 3
Differential Output High Voltage	V _{OH}	0.6	_	0.9	V	Note 2
Differential Output Low Voltage	V _{OL}	-0.9	_	-0.6	V	Note 2
Absolute Crossing Voltage	V _{CROSS}	0.25		0.55	V	Note 1, Note 4, Note 5, Note 13
Variation of V _{CROSS} Over All Rising Clock Edges	V _{CROSS_DELTA}	_	_	0.14	V	Note 1, Note 4, Note 8, Note 13
Ring Back Voltage Margin	V_{RB}	-0.1	_	0.1	V	Note 2, Note 10, Note 13
Time Before V _{RB} is Allowed	t _{STABLE}	500	_	_	ps	Note 2, Note 10, Note 13
Cycle-to-Cycle Additive Jitter	t _{CCJITTER}	_	6.5	8.1	ps	Note 2, Note 13
Absolute Maximum Output Voltage	V_{MAX}	_	_	1.15	V	Note 1, Note 6
Absolute Minimum Output Voltage	V _{MIN}	-0.3	_	_	V	Note 1, Note 7
Output Duty Cycle	V _{DC}	48	50	52	%	When input has 50% duty cycle and V _{IN} ≥ 200 mV, Note 2
Rising to Falling Edge Matching	Rise-Fall Matching	_	_	20	%	Note 1, Note 11
Clock Source DC Impedance (OUTx_p) for parts with 100Ω differential embedded impedance	Z _{C-DC_OUT_p}	40	_	60	Ω	_
Clock Source DC Impedance (OUTx_n) for parts with 100Ω differential embedded impedance	Z _{C-DC_OUT_n}	40	_	60	Ω	_

OUTPUT ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Characteristics: V_{DD} = 3.3V ±10%, 2.5V±10%; 1.8V±10% T_A = -40°C to +105°C, C_{LOAD} = 2 pF unless noted.

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Clock Source DC Impedance (OUTx_p) for parts with 85Ω differential embedded impedance	Z _{C-DC_OUT_p}	34	_	51	Ω	_
Clock Source DC Impedance (OUTx_n) for parts with 85Ω differential embedded impedance	Z _{C-DC_OUT_n}	34		51	Ω	_
Output Frequency	F _{MAX}	0	_	250	MHz	_
Output to Output Skew	t _{oosk}		_	30	ps	Note 13
Part to Part Output Skew	t _{POOSK}		_	50	ps	Note 13
Input to Output Delay	t _{IOD}	0.9	1.2	1.5	ns	
Output Enable Time	t _{EN}	_	_	3.5	cycles	Note 12
Output Disable Time	t _{DIS}	_	_	4.5	cycles	Note 12

- Note 1: Measurement taken from single ended waveform.
 - 2: Measurement taken from differential waveform.
 - 3: Measured from –150 mV to +150 mV on the differential waveform (derived from OUTx_p to OUTx_n). The signal must be monotonic through the measurement region for rise and fall time. The 300 mV measurement window is centered on the differential zero crossing. See Figure 1-5.
 - **4:** Measured at crossing point where the instantaneous voltage value of the rising edge of OUTx_p equals the falling edge of OUTx_n. See Figure 1-1.
 - **5:** Refers to the total variation from the lowest crossing point to the highest, regardless of which edge is crossing. Refers to all crossing points for this measurement. See Figure 1-1.
 - 6: Defined as the maximum instantaneous voltage including overshoot. See Figure 1-1.
 - 7: Defined as the minimum instantaneous voltage including undershoot. See Figure 1-1.
 - 8: Defined as the total variation of all crossing voltages of Rising OUTx_p and Falling OUTx_n. This is the maximum allowed variance in V_{CROSS} for any particular system. See Figure 1-2.
 - **9:** System board compliance measurements must use the test load card described in Figure 1-7. OUTx_p and OUTx_n are to be measured at the load capacitors C_{LOAD}. Single ended probes must be used for measurements requiring single ended measurements. Either single ended probes with math or differential probe can be used for differential measurements.
 - 10: T_{STABLE} is the time the differential clock must maintain a minimum ±150 mV differential voltage after rising/falling edges before it is allowed to droop back into the V_{RB} ±100 mV differential range. See Figure 1-6.
 - 11: Matching applies to rising edge rate for OUTx_p and falling edge rate for OUTx_n. It is measured using a ±75 mV window centered on the median cross point where OUTx_p rising meets OUTx_n falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations. The Rise Edge Rate of OUTx_p should be compared to the Fall Edge Rate of OUTx_n; the maximum allowed difference should not exceed 20% of the slowest edge rate. See Figure 1-3.
 - 12: Output Enable control pins are synchronous with the input clock and it takes four rising edges before outputs get enabled and five rising edges before outputs get disabled. Hence the minimum input frequency is greater than 0 Hz. Once the outputs are enabled the input clock frequency can be reduced to 0 Hz.
 - 13: Ensured by design and/or characterization, not tested in production.

JITTER AND PHASE NOISE

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Peak-to-Peak Additive Jitter	p-p A _{JRMS}	_	_	4.5	ps	Note 1, Note 2, Note 4
Additive Jitter as per PCIe 1.0 (1.5 MHz to 22 MHz)	t _{jPCle_1.0}	_	0.7	0.8	ps _{RMS}	Note 1, Note 2, Note 4
Additive Jitter as per PCle 2.0 high band (1.5 MHz to 50 MHz)	t _{jPCle_2.0_high}	_	70	90	fs _{RMS}	Note 1, Note 2, Note 4
Additive Jitter as per PCle 2.0 low band (10 kHz to 1.5 MHz)	t _{jPCle_2.0_low}	_	14	20	fs _{RMS}	Note 1, Note 2, Note 4
Additive Jitter as per PCIe 2.0 mid band (5 MHz to 16 MHz)	t _{jPCle_2.0_mid}	_	55	74	fs _{RMS}	Note 1, Note 2, Note 4
Additive Jitter as per PCle 3.0 (PLL_BW = 2 to 5 MHz, CDR = 10 MHz)	t _{jPCle_3.0}	_	18	22	fs _{RMS}	Note 1, Note 2, Note 4
Additive Jitter as per PCle 4.0 (PLL_BW = 2 to 5 MHz, CDR = 10 MHz)	t _{jPCle_4.0}	_	18	22	fs _{RMS}	Note 1, Note 2, Note 4
Additive Jitter as per PCle 5.0 (PLL_BW = 0.5 to 1.8 MHz, CDR for 32 GT/s CC)	t _{jPCle_5.0}	_	7.5	10	fs _{RMS}	Note 2, Note 3, Note 4
Additive jitter as per Intel QPI 9.6 Gbps	t _{jQPI}	_	35	45	fs _{RMS}	Note 1, Note 2, Note 4
Additive RMS jitter in 1 MHz to 20 MHz band		_	51	66	fs _{RMS}	Note 1, Note 2, Note 4 (100 MHz clock)
Additive Rivis filter III 1 Minz to 20 Minz band	t _{j_1M_} 20M	_	40	54	fs _{RMS}	Note 1, Note 2, Note 4 (133 MHz clock)
Additive DMC litter in 12 kHz to 20 MHz hand	ti 12k 20M	_	52	68	fs _{RMS}	Note 1, Note 2, Note 4 (100 MHz clock)
Additive RMS jitter in 12 kHz to 20 MHz band	tj_12k_20M	_	44	58	fs _{RMS}	Note 1, Note 2, Note 4 (133 MHz clock)
Noise Floor	NE		-165	-163	dBc/Hz	Note 1, Note 2, Note 4 (100 MHz clock)
Noise Floor	NF		-165	-163	dBc/Hz	Note 1, Note 2, Note 4 (133 MHz clock)

- Note 1: Measured into AC test load as per Figure 1-7.
 - 2: Measured from differential crossing point to differential crossing point.
 - 3: Measured with 50Ω termination in instrument without a test load.
 - **4:** Ensured by design and/or characterization, not tested in production.

TEMPERATURE SPECIFICATIONS

Parameters	Symbol	16 Pin VQFN 3 mmx3 mm	Unit	Condition
Temperature Ranges				
		35.7		Still air
Junction to Ambient Thermal Resistance	θ_{JA}	30.8	°C/W	1m/s airflow
		28.6		2.5m/s airflow
Junction to Board Thermal Resistance	θ_{JB}	5	°C/W	_
Junction to Case Thermal Resistance	$\theta_{\sf JC}$	49.5	°C/W	_
Thermal Characterization, Junction to Top of Package	Ψ_{JT}	3	°C/W	Still air

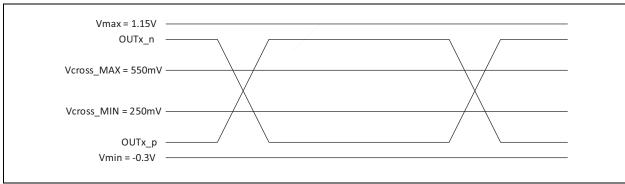


FIGURE 1-1: Single-Ended Measurement Points for Absolute Cross Point and Swing.

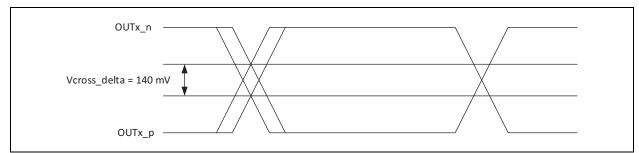


FIGURE 1-2: Single-Ended Measurement Points for Delta Cross Point.

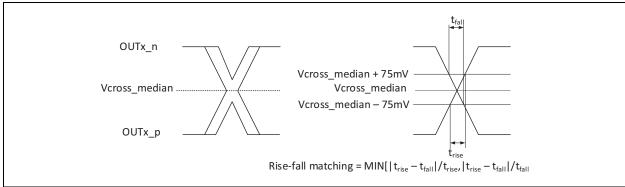


FIGURE 1-3: Single-Ended Measurement Points for Rise and Fall Time Matching.

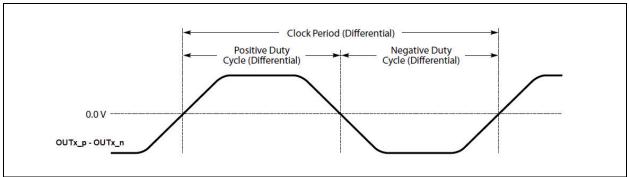


FIGURE 1-4: Differential Measurement Points for Duty Cycle and Period.

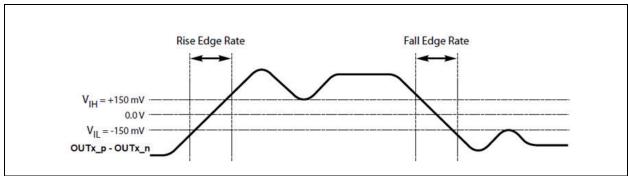


FIGURE 1-5: Differential Measurement Points for Rise and Fall Time.

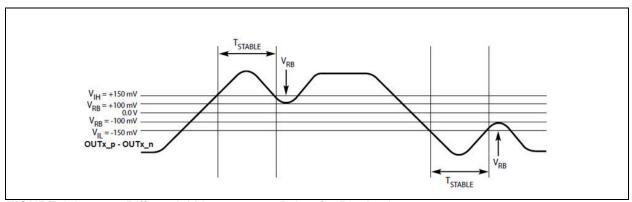


FIGURE 1-6: Differential Measurement Points for Ringback.

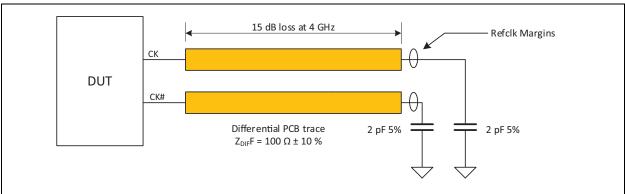


FIGURE 1-7: PCIe Test Load.

2.0 TYPICAL OPERATING CHARACTERISTICS

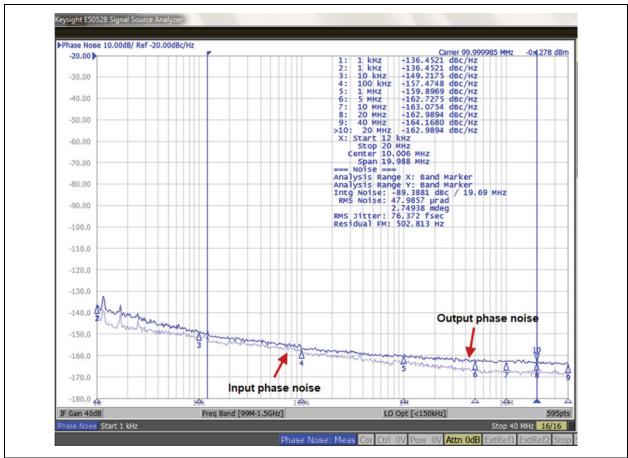


FIGURE 2-1: Typical Expected Phase Noise.

3.0 PIN DESCRIPTIONS

All device inputs and outputs are LP-HCSL unless described otherwise. The Type column uses the following symbols:

- I: Input
- IPD: Input with 100 k Ω internal pull-down resistor
- O: Output
- P: Power supply

The descriptions of the pins are listed in Table 3-1.

TABLE 3-1: SYA75604A/B AND SYA75603A/B PIN FUNCTION TABLE

IABLE 3-1:	J 17/300-	יט מוא טיאי	7/300	3A/B PIN FUNCTION TABLE				
Pin Number	Pin Name SYA75604A/B	Pin Name SYA75603A/B	Туре	Description				
Input Refere	ence							
1	IN_p	IN_p		Differential/Single Ended Input Reference				
				Input frequency range >0 Hz to 250 MHz				
2	IN_n	IN_n	I	Note 1: >0 Hz means frequency higher than DC. Output Enable control pins (OExb) need 3.5 clock cycles of the input clock to enable and 4.5 clock to disable the output. This feature ensures glitch free transition of the outputs.				
				Note 2: The differential input has hysteresis of 30 mV that prevents outputs from randomly toggling when both p and n inputs are at the same voltage level. For example, when p and n inputs are held low, as in the case when the buffer is driven from an HCSL driver that is disabled.				
Output Clocks								
4	OUT0_p	NC						
5	OUT0_n	NC		Ultra-Low Additive Jitter Differential Outputs 0 to 1				
7	OUT1_p	NC		(SYA75603A/B) and 0 to 3 (SYA75604A/B)				
8	OUT1_n	NC	0	Output fraguency range >0 Hz to 250 MHz				
10	OUT2_p	OUT0_p	0	Output frequency range >0 Hz to 250 MHz				
11	OUT2_n	OUT0_n		NC are no connect pins. They are not bonded to the die but they				
14	OUT3_p	OUT1_p		should be soldered to the board for mechanical reasons.				
15	OUT3_n	OUT1_n						
Control Inp	uts							
3	OE0b	NC		Output Enable Control				
6	OE1b	NC		N/I OF				
12	OE2b	OE0b		When OExb is low the output x where $x = \{0,1\}$ for SYA75603A/B and $x = \{0,1,2,3\}$ for SYA75604A/B is active.				
16	OE3b	OE1b	IPD	OExb is synchronous and takes 3.5 clock cycles of the input clock to enable and 4.5 clock to disable the output. OExb pins are pulled-down with 100 kΩ resistor NC are no connect pins. They are not bonded to the die but they should be soldered to the board for mechanical reasons.				
Power and	Ground							
13	VDD	VDD	Р	Positive Supply Voltage: Connect to either 3.3V, 2.5V, or 1.8V supply.				
9 ePad	GND	GND	Р	Ground: Connect to ground.				

4.0 FUNCTIONAL DESCRIPTION

The SYA75603A/03B/604A/04B are PCIe clock buffers with ultra-low additive jitter. They can be used in all PCIe 1/2/3/4/5 common clock and SRIS applications.

SYA75603A/03B and SYA75604A/04B are two and four output PCle clock buffers with glitch free per-output enable/disable control hardware pins. Both devices are packaged in 3 mm x 3 mm VQFN.

They have embedded low-dropout regulators (LDO) for superior power noise supply rejection. They support 1.8V, 2.5V, and 3.3V supplies with tolerance of ±10% which exceeds ±9% required by PCIe Card Electro Mechanical Specification.

4.1 Clock Input

Please refer to the Functional Block Diagrams for how to terminate different signals fed to the input of the device.

Figure 4-1 and Figure 4-2 show how to terminate input of the device in most common cases: Low Power HCSL (LPHCSL), HCSL, and single ended LVCMOS.

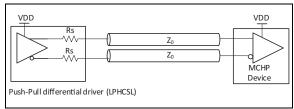


FIGURE 4-1: Input Driven by LPHCSL Driver.

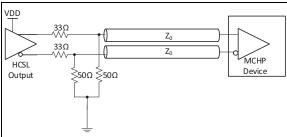


FIGURE 4-2: Input Driven by HCSL Driver.

Figure 4-3 shows how to terminate a single ended output such as LVCMOS. This example assumes 50Ω transmission line which is the most common for single ended CMOS signaling. Ideally, resistors R1 and R2 should be 100Ω each and R_O+R_S should be 50Ω so that the transmission line is terminated at both ends with characteristic impedance. If the driving strength of the output driver is not sufficient to drive low impedance, the value of series resistor R_S should be increased. This will reduce the voltage swing at the input but this should be fine as long as the input voltage swing requirement is not violated (0.3V). The source

resistors of R_S = 270 Ω could be used for standard LVCMOS driver. This will provide 516 mV of voltage swing for 3.3V LVCMOS driver with load current of (3.3V/2) * $(1/(270\Omega + 50\Omega))$ = 5.16 mA.

For optimum performance both differential input pins (_p and _n) need to be DC biased to the same voltage. Hence, the ratio R1/R2 should be equal to the ratio R3/R4.

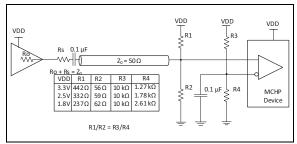


FIGURE 4-3: Input Driven from a Single-Ended CMOS Output.

The differential input has hysteresis of 30 mV that prevents outputs from randomly toggling when both p and n inputs are at the same voltage level. For example, when p and n inputs are held low, as in the case when the buffer is driven from an HCSL driver that is disabled.

4.2 Clock Outputs

Differential outputs have embedded termination resistors as shown in Figure 4-4. This provides significant saving relative to traditional current based HCSL outputs which require four resistors per differential output.

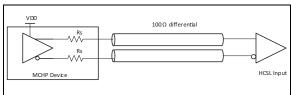


FIGURE 4-4: Terminating Differential Outputs.

Embedded termination resistors in SYA75603A/03B/604A/04B are matched for 100 Ω differential transmission line.

4.3 Output Enable

Each output of SYA75603A/03B/604A/04B has an active-low Output Enable (OExb) control pin. The Output Enable and Disable function is synchronous with the input clock, which results in glitchless transitions as shown in Figure 4-5 and Figure 4-6. The OExb is sampled on the falling edge of the differential input (or falling edge of IN_p signal). It takes 3.5 clock cycles of the input clock to enable an output and 4.5 clock cycles to disable the output, after the change of OExb is sampled.

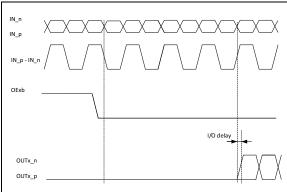


FIGURE 4-5: OExb Assertion (Output Enable) Timing Diagram.

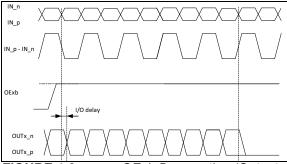
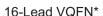
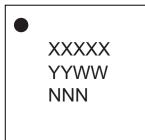


FIGURE 4-6: OExb Deassertion (Output Disable) Timing Diagram.

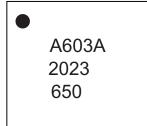
5.0 PACKAGING INFORMATION

5.1 **Package Marking Information**





Example



Legend: XX...X Product code or customer-specific information

Υ Year code (last digit of calendar year) ΥY Year code (last 2 digits of calendar year) WW Week code (week of January 1 is week '01')

NNN Alphanumeric traceability code

Pb-free JEDEC® designator for Matte Tin (Sn) (e3)

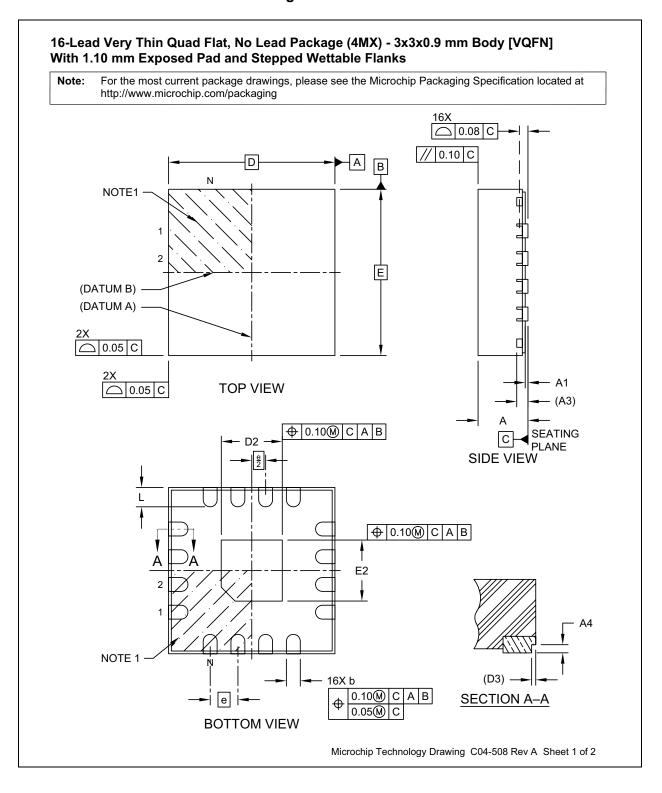
This package is Pb-free. The Pb-free JEDEC designator (@3) can be found on the outer packaging for this package.

•, ▲, ▼ Pin one index is identified by a dot, delta up, or delta down (triangle mark).

In the event the full Microchip part number cannot be marked on one line, it will Note: be carried over to the next line, thus limiting the number of available characters for customer-specific information. Package may or may not include the corporate logo.

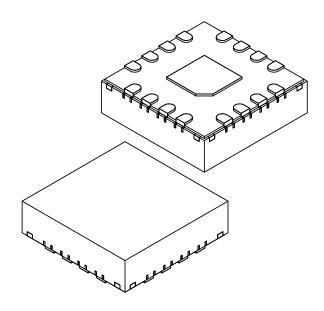
Underbar (_) and/or Overbar (_) symbol may not be to scale.

16-Lead VQFN 3.0 mm x 3.0 mm Package Outline and Recommended Land Pattern



16-Lead Very Thin Quad Flat, No Lead Package (4MX) - 3x3x0.9 mm Body [VQFN] With 1.10 mm Exposed Pad and Stepped Wettable Flanks

For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	MILLIMETERS			
Dimension	MIN	NOM	MAX		
Number of Terminals	N		16		
Pitch	е		0.50 BSC		
Overall Height	Α	0.80	0.85	0.90	
Standoff	A1	0.00	0.02	0.05	
Terminal Thickness	A3	0.203 REF			
Overall Length	D	3.00 BSC			
Exposed Pad Length	D2	1.00 1.10 1.20			
Overall Width	E		3.00 BSC		
Exposed Pad Width	E2	1.00	1.10	1.20	
Terminal Width	b	0.20	0.25	0.30	
Terminal Length	L	0.25 0.35 0.45			
Wettable Flank Step Length	D3	0.05 REF			
Wettable Flank Step Height	A4	0.10	-	0.19	

Notes:

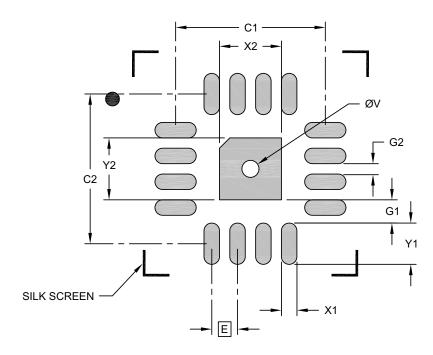
- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances. REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-508 Rev A Sheet 2 of 2

16-Lead Very Thin Quad Flat, No Lead Package (4MX) - 3x3x0.9 mm Body [VQFN] With 1.10 mm Exposed Pad and Stepped Wettable Flanks

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension	Limits	MIN	NOM	MAX
Contact Pitch	E			
Optional Center Pad Width	X2			1.20
Optional Center Pad Length	Y2			1.20
Contact Pad Spacing	C1		2.90	
Contact Pad Spacing	C2		2.90	
Contact Pad Width (X16)	X1			0.30
Contact Pad Length (X16)	Y1			0.80
Contact Pad to Center Pad (X16)	G1	0.45		
Contact Pad to Contact Pad (X12)	G2	0.20		
Thermal Via Diameter	V		0.33	

Notes:

- Dimensioning and tolerancing per ASME Y14.5M
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
- 2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

Microchip Technology Drawing C04-2508 Rev A

APPENDIX A: REVISION HISTORY

Revision A (October 2021)

• Initial release of SYA75603A/03B/604A/04B as Microchip data sheet DS20006438A.

Revision B (July 2022)

• Added information specific to the 85Ω devices to the Current Consumption section of the Electrical Characteristics table.

NOTES:		

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

PART NO.	xxx	[-XX]	xxx	Example	es:	
Device	Package	Media Type	Automotive Suffix	a) SYA75603ATWL- VAO:		2 Output Ultra-Low Additive Jitter PCIe 1/2/3/4/5 85Ω Clock Buffer, 16- Lead 3 mm x 3 mm VQFN, 120/
Device:	85Ω SYA75603B: 2 Ou 100Ω SYA75604A: 4 Ou 85Ω SYA75604B: 4 Ou 100Ω	tput Ultra-Low Additive Clock Buffer for Autom tput Ultra-Low Additive Clock Buffer for Autor tput Ultra-Low Additive Clock Buffer for Autor tput Ultra-Low Additive Clock Buffer for Autor Clock Buffer for Autor ad 3 mm x 3 mm VQFN	otive Jitter PCIe 1/2/3/4/5 motive Jitter PCIe 1/2/3/4/5 otive Jitter PCIe 1/2/3/4/5 motive	VÁO:	5604BTWL- 5604ATWL-	Tube, Standard Automotive 4 Output Ultra-Low Additive Jitter PCle 1/2/3/4/5 100Ω Clock Buffer, 16-Lead 3 mm x 3 mm VQFN, 120/ Tube, Standard Automotive 4 Output Ultra-Low Additive Jitter PCle 1/2/3/4/5 85Ω Clock Buffer, 16- Lead 3 mm x 3 mm VQFN, 3,300/ Reel, Standard Automotive
Media Type: Automotive Suffix:	<pre><blank> = 120/Tube T/R = 3,300/Reel VXX = Automotive Suffix in which "XX" is assigned by Microchip. Standard value "AO" is for standard automotive part.</blank></pre>		Note 1:	1: Tape and Reel identifier only appears in the catalog part number description. This identifier is used for ordering purposes and is not printed on the device package. Check with your Microchip Sales Office for package availability with the Tape and Reel option.		

NOTES:		
NOTES:		

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